

# DB151 THRU DB157

## SINGLE-PHASE GLASS PASSIVATED SILICON BRIDGE RECTIFIER



康比電子  
HORNBY ELECTRONIC

**REVERSE VOLTAGE:** 50 to 1000 VOLTS  
**FORWARD CURRENT:** 1.5 AMPERE

### FEATURES

- Plastic material has Underwriters Laboratory Flammability Classification 94V-0
- High surge overload rating of 50 Amperes peak
- Ideal for printed circuit board
- Glass passivated chip junction

### MECHANICAL DATA

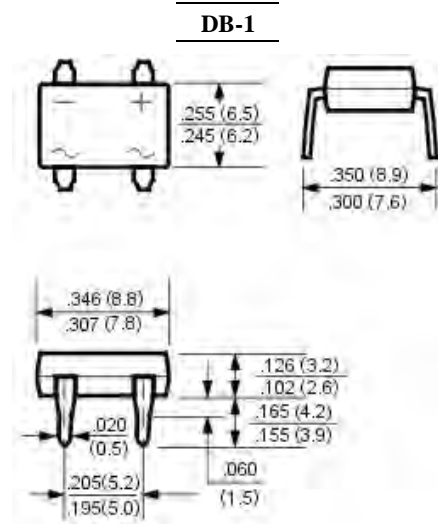
Case: Molded plastic, DB-1

Epoxy: UL 94V-O rate flame retardant

Terminals: Leads solderable per MIL-STD-202, method 208 guaranteed

Mounting position: Any

Weight: 0.02ounce, 0.4gram



Dimensions in inches and (millimeters)

### Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

|  | Symbols         | DB151       | DB152 | DB153 | DB154 | DB155 | DB156 | DB157 | Units |
|--|-----------------|-------------|-------|-------|-------|-------|-------|-------|-------|
| Maximum Recurrent Peak Reverse Voltage   | $V_{RRM}$       | 50          | 100   | 200   | 400   | 600   | 800   | 1000  | Volts |
| Maximum RMS Voltage  | $V_{RMS}$       | 35          | 70    | 140   | 280   | 420   | 560   | 700   | Volts |
| Maximum DC Blocking Voltage  | $V_{DC}$        | 50          | 100   | 200   | 400   | 600   | 800   | 1000  | Volts |
| Maximum Average Forward Rectified Current at $T_A=40^\circ\text{C}$ (Note 2)                           | $I_{(AV)}$      | 1.5         |       |       |       |       |       |       | Amp   |
| Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)      | $I_{FSM}$       | 50          |       |       |       |       |       |       | Amp   |
| Maximum Forward Voltage at 1.5A DC and 25°C  | $V_F$           | 1.1         |       |       |       |       |       |       | Volts |
| Maximum Reverse Current at $T_A=25^\circ\text{C}$ at Rated DC Blocking Voltage $T_A=125^\circ\text{C}$ |                 | 5.0<br>500  |       |       |       |       |       |       | uAmp  |
| Typical Junction Capacitance (Note 1)  | $C_J$           | 25          |       |       |       |       |       |       | pF    |
| Typical Thermal Resistance (Note 2)  | $R_{\theta JA}$ | 40          |       |       |       |       |       |       | °C/W  |
| Typical Thermal Resistance (Note 2)  | $R_{\theta JL}$ | 15          |       |       |       |       |       |       | °C/W  |
| Operating and Storage Temperature Range  | $T_J, T_{stg}$  | -55 to +150 |       |       |       |       |       |       | °C    |

### NOTES:

1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.

2- Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.5 x 0.5" (13 x 13mm) copper pads

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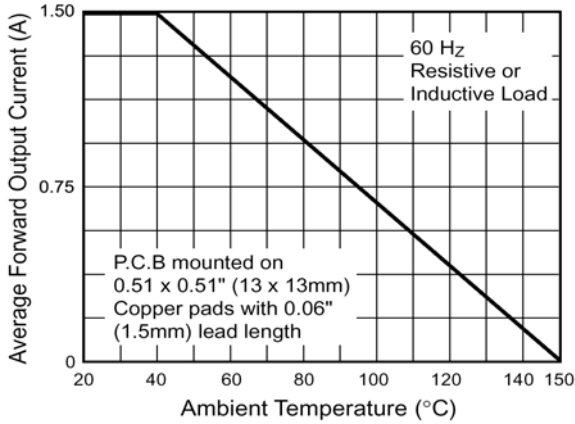
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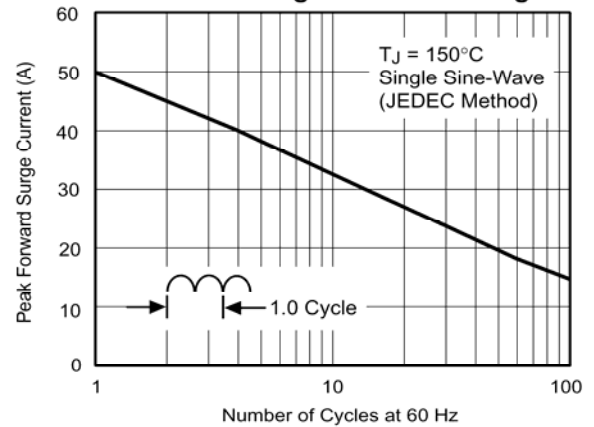
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### RATINGS AND CHARACTERISTIC CURVES

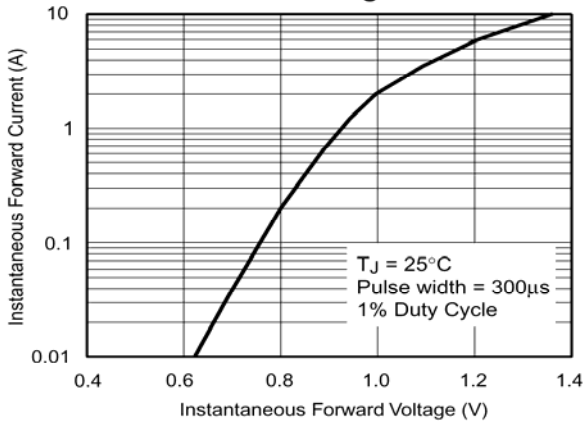
**Fig. 1 - Derating Curve Output Rectified Current**



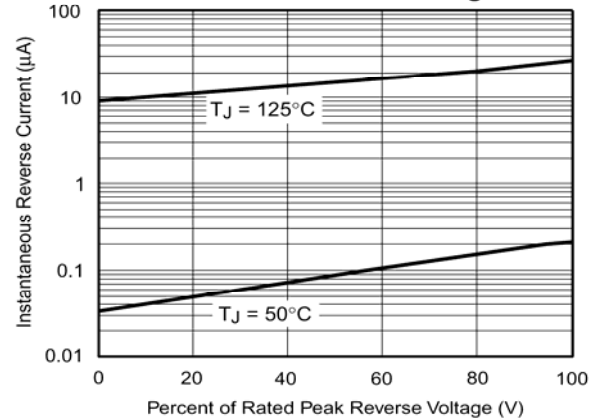
**Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Leg**



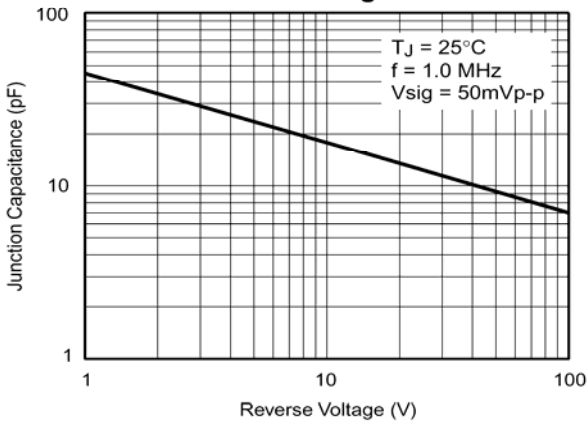
**Fig. 3 - Typical Forward Characteristics Per Leg**



**Fig. 4 - Typical Reverse Leakage Characteristics Per Leg**



**Fig. 5 - Typical Junction Capacitance Per Leg**



**Fig. 6 - Typical Transient Thermal Impedance**

